UNISONIC TECHNOLOGIES CO., LTD

SK1816M

LINEAR INTEGRATED CIRCUIT

BIPOLAR LATCH TYPE HALL EFFECT FOR HIGH-TEMPERATURE **OPERATION**

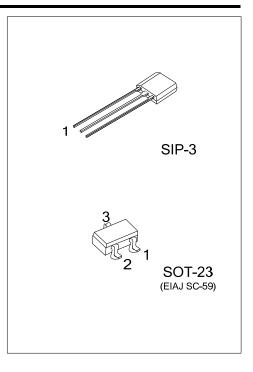
DESCRIPTION

The UTC SK1816M is a semiconductor integrated circuit utilizing the Hall effect. It designed to operate in the alternating magnetic field especially at low supply voltage and operation over extended temperature ranges to +125°C.

This Hall IC is suitable for application to various kinds of sensors, contact-less switches, such as Speed sensor, Position sensor, Rotation sensor, Contact-less sensor, and Motor control.

FEATURES

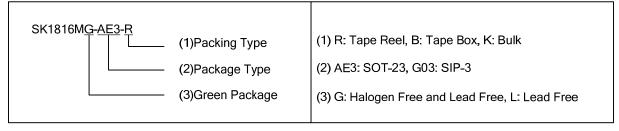
- * Wide Temperature Operation Range of -30°C ~ +125°C
- * Alternating Magnetic Field Operation
- * Built-in Protection Diode
- * TTL and MOS IC are Directly Drivable by the Output
- * The life is Semi Permanent because it Employs Contact-Less Parts
- * SIP-3 and SOT-23 Package are Available.



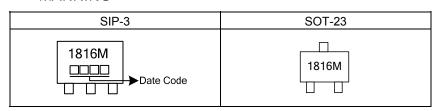
ORDERING INFORMATION

Ordering Number		Dookaga	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
SK1816ML-AE3-R	SK1816MG-AE3-R	SOT-23	0	I	G	Tape Reel	
SK1816ML-G03-B	SK1816MG-G03-B	SIP-3	- 1	G	0	Tape Box	
SK1816ML-G03-K	SK1816MG-G03-K	SIP-3	I	G	0	Bulk	

Note: Pin Assignment: I: V_{CC} O: V_{OUT} G: GND

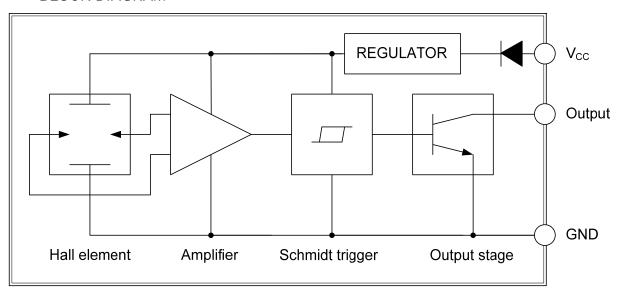


MARKING



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■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage		V _{CC}	2.5 ~ 20	V
Supply Current		Icc	6	mA
Circuit Current		l _o	20	mA
D Bississities	SIP-3	-	400	mW
Power Dissipation	SOT-23	P _D	200	400 mW 200 mW
Operating Temperature		T _{OPR}	-30 ~ +125	°C
Storage Temperature		T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT	
Low Lovel Output Voltage	V _{OL}	V _{CC} =16V, I _{OUT} =12mA, B=30mT		0.2	0.7	V	
Low-Level Output Voltage		V _{CC} =3.6V, I _{OUT} =12mA, B=30mT		0.3	0.7	V	
Output Leakage Current	I _{LEAK}	V _{CC} =16V, B=-30mT		1	10	μΑ	
Supply Current	I _{CC}	V _{CC} =16V		3.5	6	mA	
Supply Current		V _{CC} =3.6V		3	6	mA	
Output Switching Time	T_R	V_{CC} =16V, R_L =10K Ω , C_L =10pF			5	μS	
Output Switching Time	T_F	V_{CC} =16V, R_L =10K Ω , C_L =10pF			1	μS	
MAGNETIC CHARACTERISTICS							
Operate Point	B _{OP}	At T _A =25°C			5	mT	
Release Point	B_RP	At T _A =25°C			-5	mT	
Hysteresis	B _{HYS}	At T _A =25°C		5.5	10	mT	

Note: 1. Bop=operate point (output turns ON); BRP =release point (output turns OFF); BHYS =hysteresis(Bop – BRP). As used here, negative flux densities are defined as less than zero (algebraic convention). Typical values are at T_A=25°C and Vcc=12V.

^{2. 1}mT=10 gauss

■ PACKAGE INFORMATION

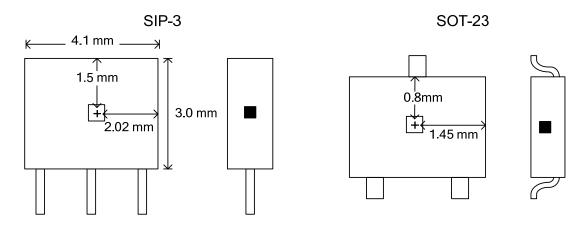


Fig. 1 SENSOR LOCATIONS

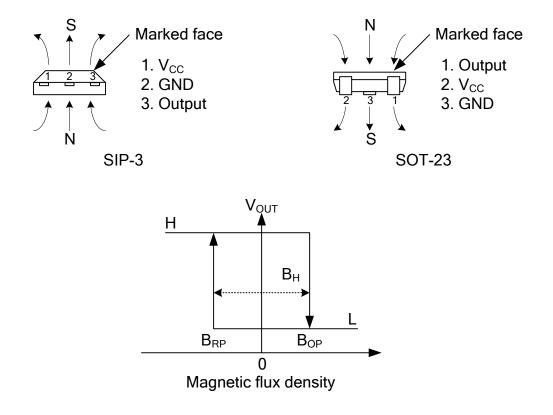
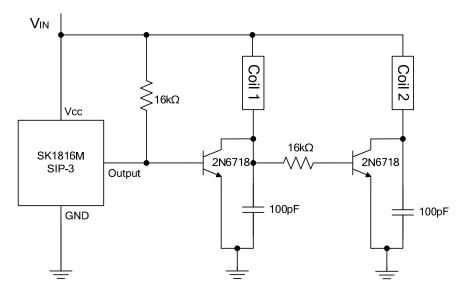
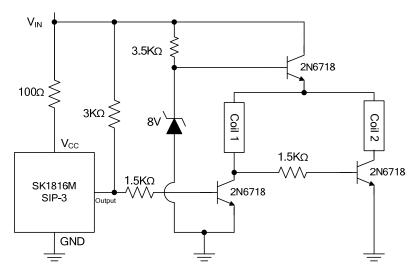


Fig. 2 APPLYING DIRECTION OF MAGNETIC FLUX

■ TYPICAL APPLICATION CIRCUIT

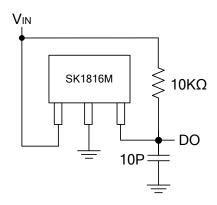


FOR DC FAN 1

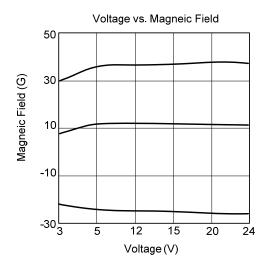


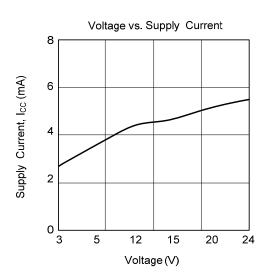
FOR DC FAN 2

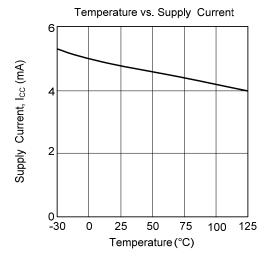
■ TEST CIRCUIT

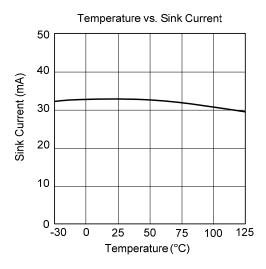


■ TYPICAL CHARACTERISTICS









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